

Product Summary

$V_{(BR)DSS}$	$R_{DS(on)TYP}$	I_D
100V	2.1mΩ@10V	220A

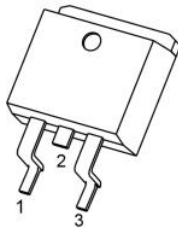
Feature

- Fast Switching
- Low Gate Charge and Rds on
- Advanced Split Gate Trench Technology
- 100% Single Pulse avalanche energy Test

Applications

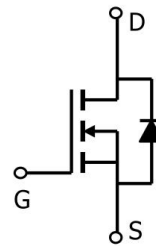
- PWM Application
- Hard switched and high frequency circuits
- Power Management

Package

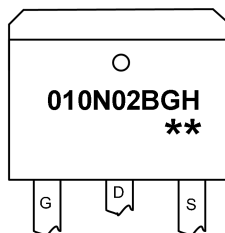


TO-263(1:G 2:D 3:S)

Circuit diagram



Marking



010N02BGH
**

=Device Code
=Week Code

**Absolute maximum ratings (Ta=25°C, unless otherwise noted)**

Parameter	Symbol	Rating	Units
Drain-Source Voltage	V _{DS}	100	V
Gate-Source Voltage	V _{GS}	±20	V
Continuous Drain Current (Tc=25°C)	I _D	220	A
Continuous Drain Current (Tc=100°C)	I _D	155	A
Pulsed Drain Current	I _{DM}	880	A
Single Pulse Avalanche Energy ¹	E _{AS}	1458	mJ
Total Power Dissipation ² (Tc=25°C)	P _D	300	W
Thermal Resistance Junction-Case	R _{θJC}	0.41	°C/W
Storage Temperature Range	T _{STG}	-55 to 150	°C
Operating Junction Temperature Range	T _J	-55 to 150	°C

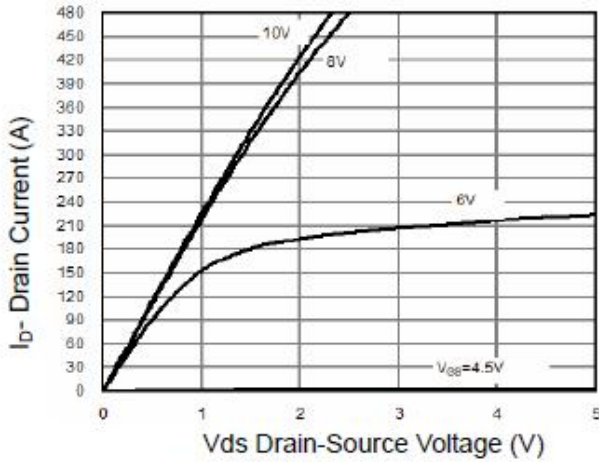
Electrical characteristics (Ta=25°C, unless otherwise noted)

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit
Static Characteristics						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V, I _D =250uA	100	---	---	V
Drain-Source Leakage Current	I _{DSS}	V _{DS} =80V, V _{GS} =0V, T _J =25°C	---	---	1	uA
Gate-Source Leakage Current	I _{GSS}	V _{GS} =±20V, V _{DS} =0V	---	---	±100	nA
Gate Threshold Voltage	V _{GS(th)}	V _{GS} =V _{DS} , I _D =250uA	2.7	3.2	4.3	V
Static Drain-Source On-Resistance	R _{DS(ON)}	V _{GS} =10V, I _D =125A	---	2.1	2.7	mΩ
Dynamic characteristics						
Input Capacitance	C _{iss}	V _{DS} =50V, V _{GS} =0V, f=1MHz	---	11531	---	pF
Output Capacitance	C _{oss}		---	1489	---	
Reverse Transfer Capacitance	C _{rss}		---	72	---	
Switching Characteristics						
Total Gate Charge (4.5V)	Q _g	V _{DS} =50V, V _{GS} =10V, I _D =125A	---	158	---	nC
Gate-Source Charge	Q _{gs}		---	51	---	
Gate-Drain Charge	Q _{gd}		---	27	---	
Turn-On Delay Time	T _{d(on)}	V _{DD} =50V, V _{GS} =10V, R _G =1.6Ω, I _D =125A	---	25	---	ns
Rise Time	T _r		---	75	---	
Turn-Off Delay Time	T _{d(off)}		---	89	---	
Fall Time	T _f		---	29	---	
Diode Characteristics						
Diode Forward Voltage ²	V _{SD}	V _{GS} =0V, I _S =1A, T _J =25°C	---	---	1.2	V
Reverse recover time	T _{rr}	I _{SD} =180A, di/dt=100A/us, V _{dd} =80, T _J =25°C	---	86	---	ns
Reverse recovery charge	Q _{rr}		---	201	---	nC
Reverse recovery current	I _{RSM}		---	5	---	A

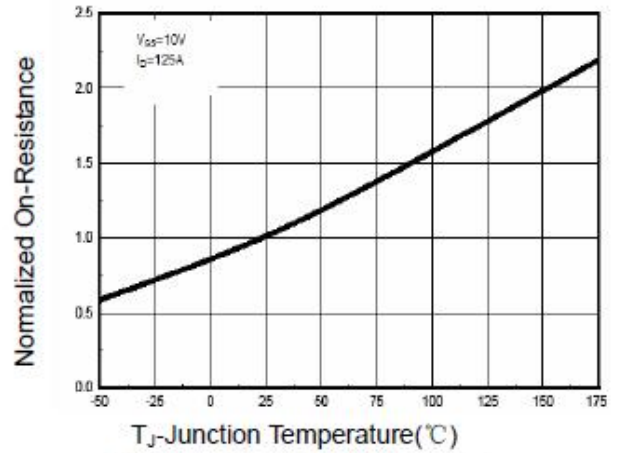
Note :

- The EAS data shows Max. rating . The test condition is V_{DD}=50V, V_{GS}=10V, L=0.5mH, R_G=25Ω
- The power dissipation is limited by 150°C junction temperature

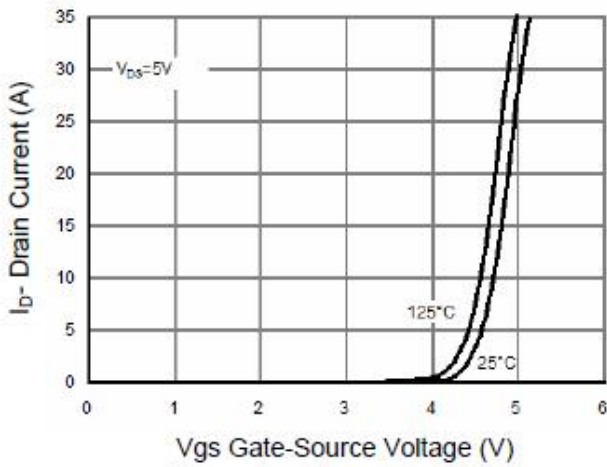
Typical Characteristics



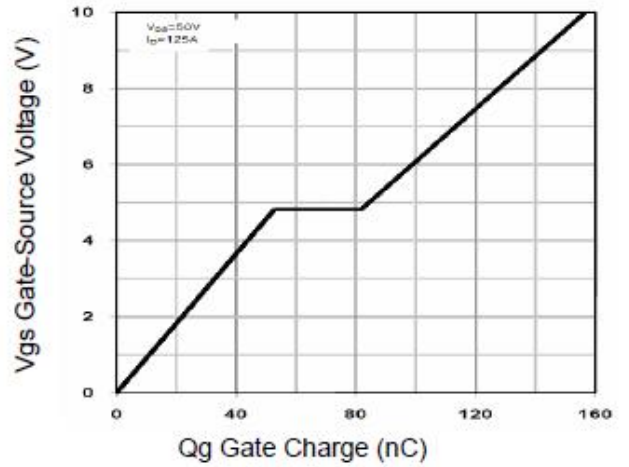
Output Characteristics



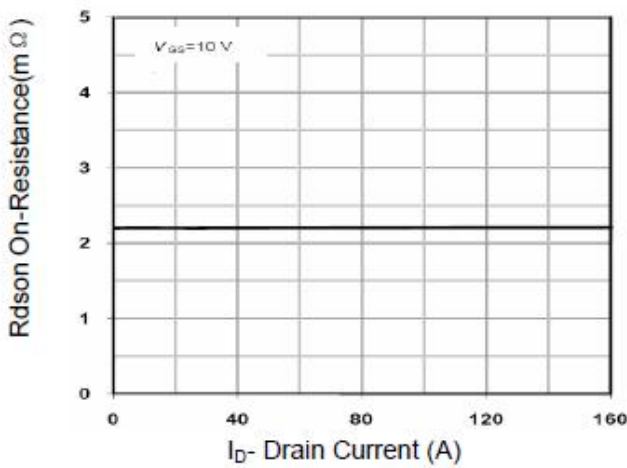
R_{dson} -Junction Temperature



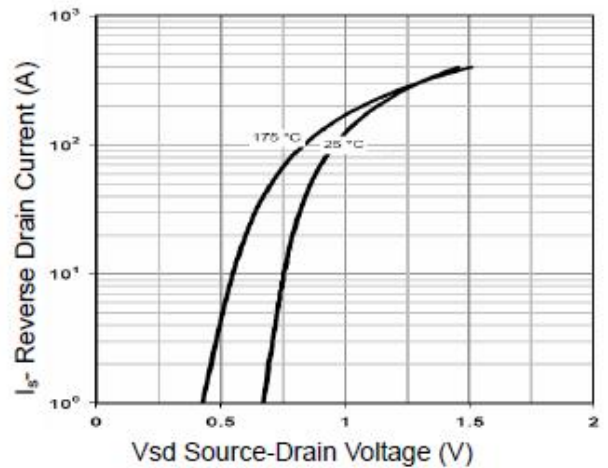
Transfer Characteristics



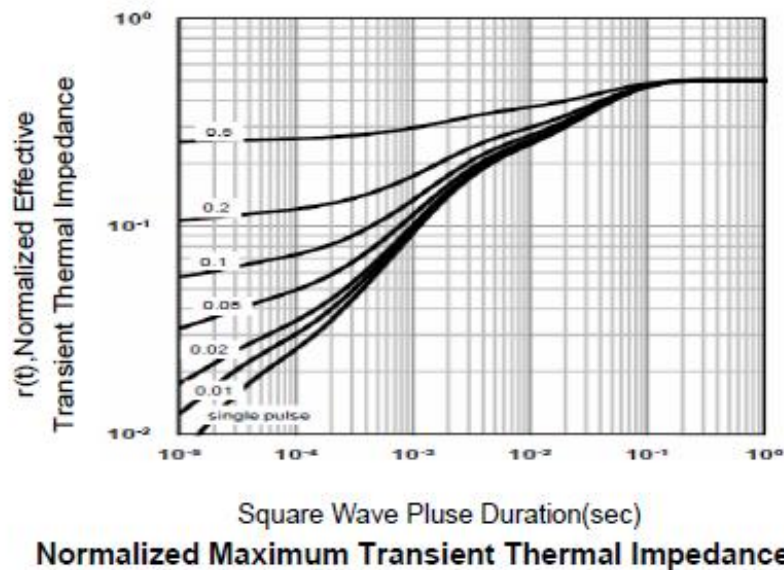
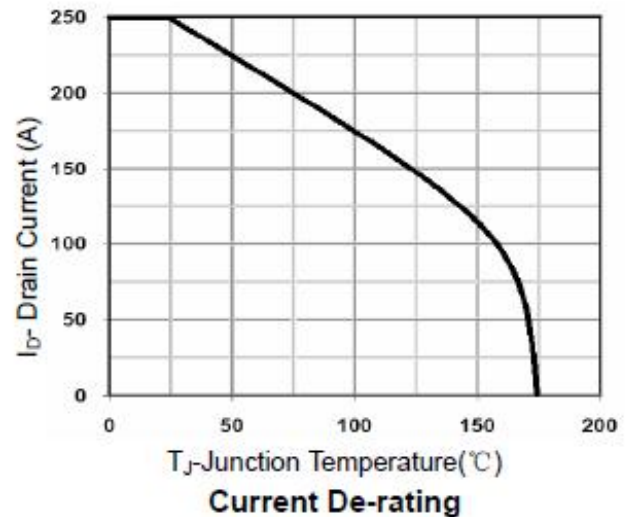
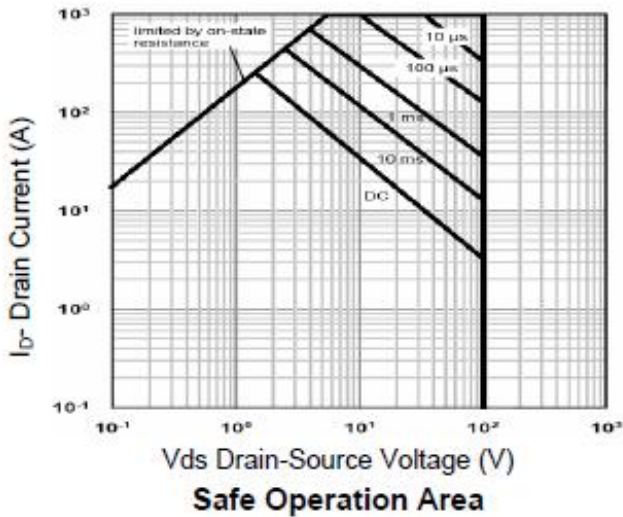
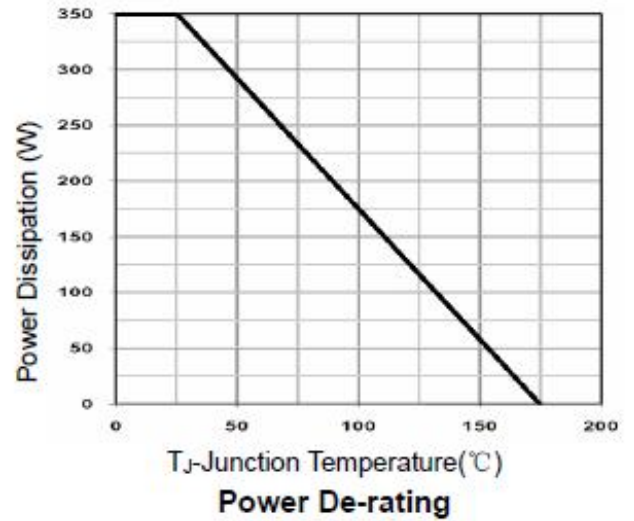
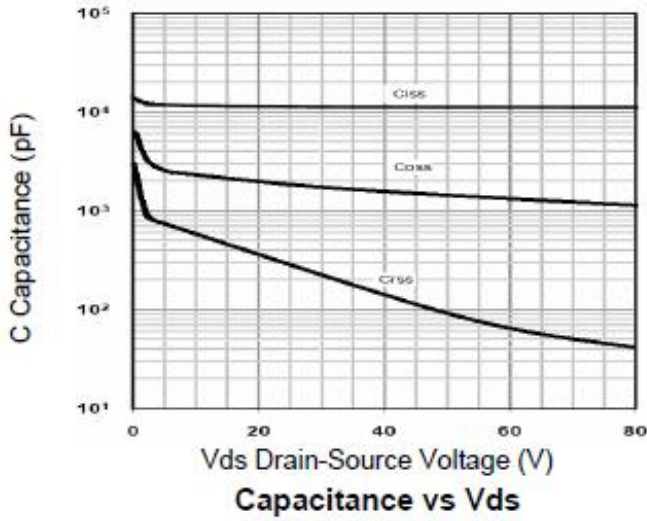
Gate Charge



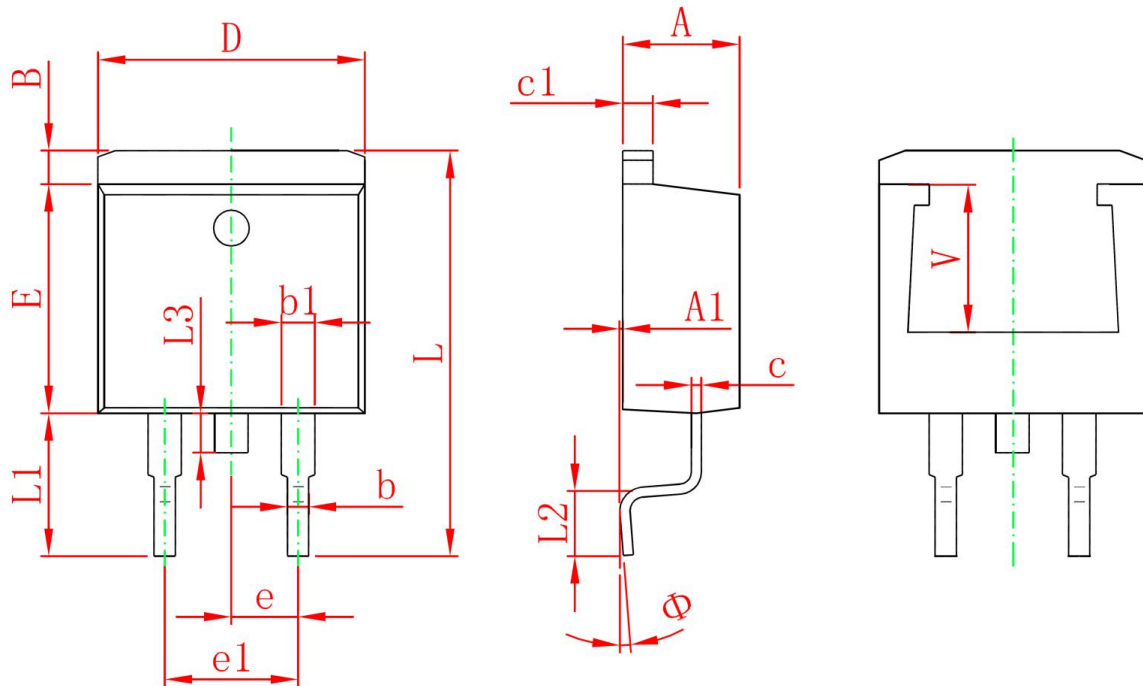
R_{dson} - Drain Current



Source- Drain Diode Forward



TO-263 Package Information



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	4.470	4.670	0.176	0.184
A1	0.000	0.150	0.000	0.006
B	1.120	1.420	0.044	0.056
b	0.710	0.910	0.028	0.036
b1	1.170	1.370	0.046	0.054
c	0.310	0.530	0.012	0.021
c1	1.170	1.370	0.046	0.054
D	10.010	10.310	0.394	0.406
E	8.500	8.900	0.335	0.350
e	2.540 TYP.		0.100 TYP.	
e1	4.980	5.180	0.196	0.204
L	14.940	15.500	0.588	0.610
L1	4.950	5.450	0.195	0.215
L2	2.340	2.740	0.092	0.108
L3	1.300	1.700	0.051	0.067
Φ	0°	8°	0°	8°
V	5.600 REF.		0.220 REF.	

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